

EV31C6 B 3 A 1 -28.636M TR

Absolute Pull Range — ±50ppm Minimum

Linearity — 10% Typical, 20% Maximum

Packaging Options
Tape & Reel
Nominal Frequency
28.636MHz

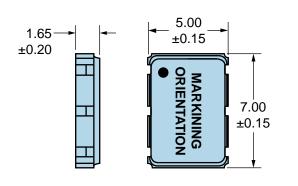
- Duty Cycle 50 ±5(%) Typical, 50 ±10(%)

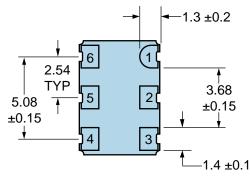
| Nominal Frequency | 28.636MHz | |
|---------------------------------------|--|--|
| Frequency Tolerance/Stability | ±50ppm Maximum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, Shock, and Vibration.) | |
| Aging at 40°C | ±2ppm/First year typical, ±10ppm/10 Years Maximum | |
| Operating Temperature Range | -40°C to +85°C | |
| Supply Voltage | 5.0Vdc ±10% | |
| Input Current | 35mA Maximum | |
| Output Voltage Logic High (Voh) | 90% of Vdd Minimum (IOH = -4mA) | |
| Output Voltage Logic Low (Vol) | 10% of Vdd Maximum (IOL = +4mA) | |
| Rise/Fall Time | 5nSec Maximum (Measured at 0.4Vdc to 2.4Vdc with TTL Load; Measured at 20% to 80% of waveform with HCMOS Load) | |
| Duty Cycle | 50 ±5(%) Typical, 50 ±10(%) (Measured at 1.4Vdc with TTL Load; Measured at 50% of waveform with HCMOS Load) | |
| Load Drive Capability | 10TTL Load or 30pF HCMOS Load Maximum | |
| Output Logic Type | CMOS | |
| Absolute Pull Range | ±50ppm Minimum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, Shock, Vibration, and Aging over the Control Voltage (Vc).) | |
| Control Voltage | 0.5Vdc to 4.5Vdc (Test Condition for Absolute Pull Range) | |
| Control Voltage Range | 0.0Vdc to Vdd | |
| Linearity | 10% Typical, 20% Maximum | |
| Transfer Function | Positive Transfer Characteristic | |
| Modulation Bandwidth | 10kHz Minimum (Measured at -3dB, Vc = 2.5Vdc) | |
| Input Impedance | 50kOhms Minimum | |
| Input Leakage Current | 10μA Maximum | |
| Phase Noise | -70dBc/Hz at offset of 10Hz, -100dBc/Hz at offset of 100Hz, -130dBc/Hz at offset of 1kHz, -147dBc/Hz at offset of 10kHz, -152dBc/Hz at offset of 100kHz, and -155dBc/Hz at offset of 1MHz (Typical values at Fo = 27MHz) | |
| Tri-State Input Voltage (Vih and Vil) | +0.9Vdd Minimum to Enable Output; +0.1Vdd Maximum to Disable Output (High Impedance); No Connect to Enable Output. | |
| RMS Phase Jitter | 1pSec Maximum (Fj = 12kHz to 20MHz) | |
| Start Up Time | 10mSec Maximum | |
| Storage Temperature Range | -55°C to +125°C | |

| ENVIRONMENTAL & MECHANICAL SPECIFICATIONS | | |
|---|--------------------------------------|--|
| Fine Leak Test | MIL-STD-883, Method 1014 Condition A | |
| Gross Leak Test | MIL-STD-883, Method 1014 Condition C | |
| Mechanical Shock | MIL-STD-202, Method 213 Condition C | |
| Resistance to Soldering Heat | MIL-STD-202, Method 210 | |
| Resistance to Solvents | MIL-STD-202, Method 215 | |
| Solderability | MIL-STD-883, Method 2003 | |
| Temperature Cycling | MIL-STD-883, Method 1010 | |
| Vibration | MIL-STD-883, Method 2007 Condition A | |



MECHANICAL DIMENSIONS (all dimensions in millimeters)



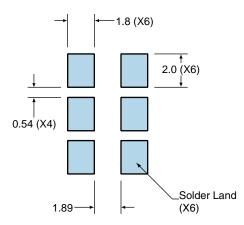


| PIN | CONNECTION |
|-----|-----------------|
| 1 | Voltage Control |
| 2 | Tri-State |
| 3 | Case Ground |
| 4 | Output |
| 5 | No Connect |
| 6 | Supply Voltage |

| LINE | MARKING |
|------|---|
| 1 | ECLIPTEK |
| 2 | 28.636M |
| 3 | XXYZZ XX=Ecliptek Manufacturing Code Y=Last Digit of Year ZZ=Week of Year |

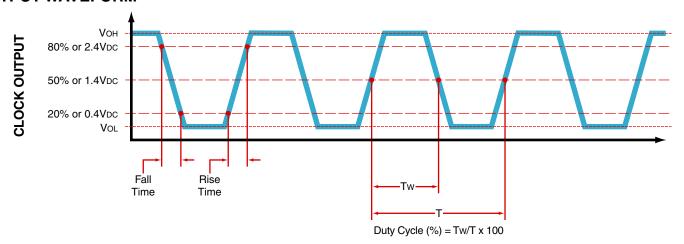
Suggested Solder Pad Layout

All Dimensions in Millimeters



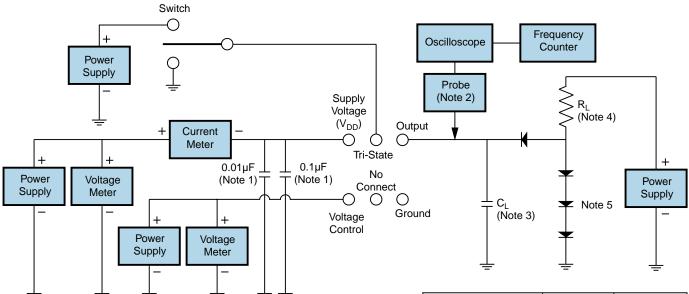
All Tolerances are ±0.1

OUTPUT WAVEFORM





Test Circuit for TTL Output



Note 1: An external $0.1\mu F$ low frequency tantalum bypass capacitor in parallel with a $0.01\mu F$ high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value $\tilde{C_L}$ includes sum of all probe and fixture capacitance.

Note 4: Resistance value R_L is shown in Table 1. See applicable specification sheet for 'Load Drive Capability'.

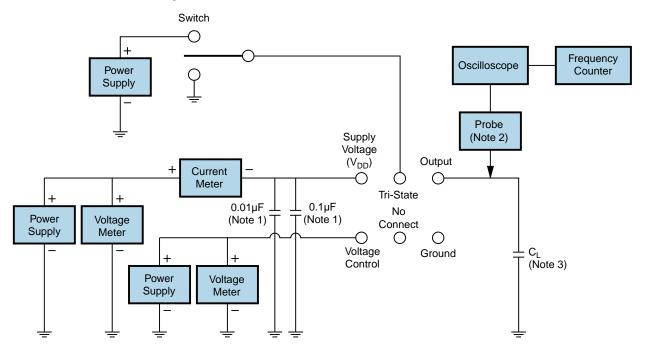
Note 5: All diodes are MMBD7000, MMBD914, or equivalent.

| Output Load Drive Capability | R _L Value (Ohms) | C _L Value (pF) |
|---------------------------------|--------------------------------|------------------------------|
| 10TTL | 390 | 15 |
| 5TTL | 780 | 15 |
| 2TTL | 1100 | 6 |
| 10LSTTL | 2000 | 15 |
| 1TTL | 2200 | 3 |

 $\label{eq:local_continuous_continuous_continuous} \begin{tabular}{ll} Table 1: R_L & Resistance & Value & and & C_L & Capacitance & Value & Vs. & Output & Load & Drive & Capability & Vs. & Capacitance & Capability & Capacitance & Capacita$



Test Circuit for CMOS Output



Note 1: An external $0.1\mu F$ low frequency tantalum bypass capacitor in parallel with a $0.01\mu F$ high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.

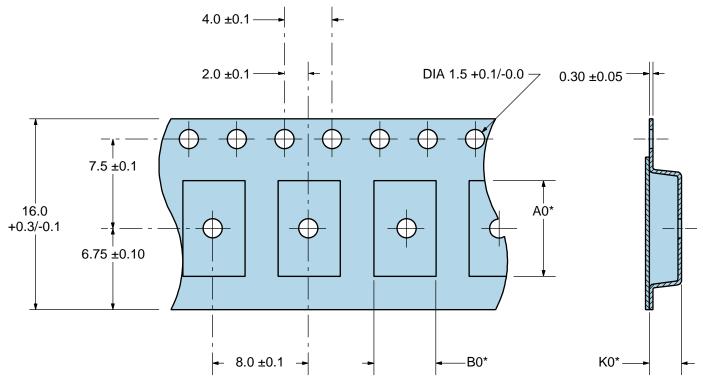
Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value C_{L} includes sum of all probe and fixture capacitance.

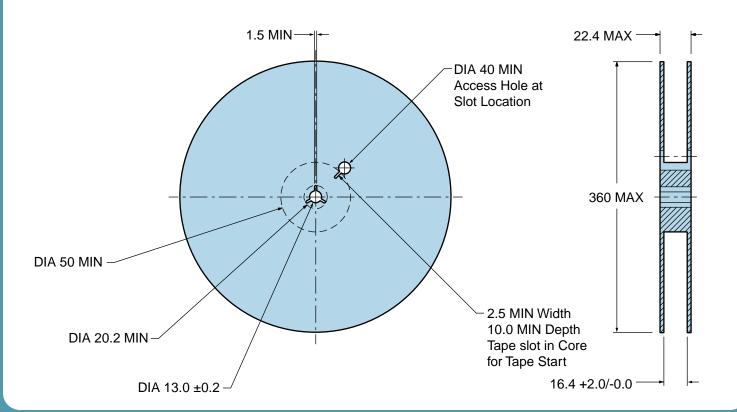


Tape & Reel Dimensions

Quantity Per Reel: 1,000 units



*Compliant to EIA 481A





Recommended Solder Reflow Methods



High Temperature Infrared/Convection

| T _S MAX to T _L (Ramp-up Rate) | 3°C/second Maximum |
|---|--------------------------------------|
| Preheat | |
| - Temperature Minimum (T _s MIN) | 150°C |
| - Temperature Typical (T _s TYP) | 175°C |
| - Temperature Maximum (T _s MAX) | 200°C |
| - Time (t _s MIN) | 60 - 180 Seconds |
| Ramp-up Rate (T _L to T _P) | 3°C/second Maximum |
| Time Maintained Above: | |
| - Temperature (T∟) | 217°C |
| - Time (t∟) | 60 - 150 Seconds |
| Peak Temperature (T _P) | 260°C Maximum for 10 Seconds Maximum |
| Target Peak Temperature (T _P Target) | 250°C +0/-5°C |
| Time within 5°C of actual peak (tp) | 20 - 40 seconds |
| Ramp-down Rate | 6°C/second Maximum |
| Time 25°C to Peak Temperature (t) | 8 minutes Maximum |
| Moisture Sensitivity Level | Level 1 |
| | |



Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 240°C

| T _S MAX to T _L (Ramp-up Rate) | 5°C/second Maximum |
|---|--|
| Preheat | |
| - Temperature Minimum (T _s MIN) | N/A |
| - Temperature Typical (T _s TYP) | 150°C |
| - Temperature Maximum (T _s MAX) | N/A |
| - Time (t _s MIN) | 60 - 120 Seconds |
| Ramp-up Rate (T _L to T _P) | 5°C/second Maximum |
| Time Maintained Above: | |
| - Temperature (T∟) | 150°C |
| - Time (t∟) | 200 Seconds Maximum |
| Peak Temperature (T _P) | 240°C Maximum |
| Target Peak Temperature (T _P Target) | 240°C Maximum 1 Time / 230°C Maximum 2 Times |
| Time within 5°C of actual peak (t _p) | 10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time |
| Ramp-down Rate | 5°C/second Maximum |
| Time 25°C to Peak Temperature (t) | N/A |
| Moisture Sensitivity Level | Level 1 |

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.